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- High-Current 3-State Outputs Drive Bus Lines Directly or up to 15 LSTTL Loads
- Bus-Structured Pinout
- Package Options Include Plastic Small-Outline (DW) and Ceramic Flat (W)
 Packages, Ceramic Chip Carriers (FK), and Standard Plastic (N) and Ceramic (J)
 300-mil DIPs

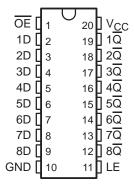
description

These 8-bit transparent D-type latches feature 3-state outputs designed specifically for driving highly capacitive or relatively low-impedance loads. They are particularly suitable for implementing buffer registers, I/O ports, bidirectional bus drivers, and working registers.

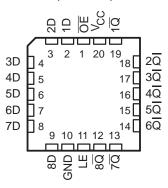
While the latch-enable (LE) input is high, the \overline{Q} outputs follow the complements of the data (D) inputs. When LE is taken low, the outputs are latched at the inverses of the levels set up at the D inputs.

A buffered output-enable (OE) input places the eight outputs in either a normal logic state (high or low logic levels) or the high-impedance state. In the high-impedance state, the outputs neither load nor drive the bus lines significantly. The high-impedance state and increased high logic level provide the capability to drive bus lines without interface or pullup components.

SN54HC563...J OR W PACKAGE SN74HC563...DW OR N PACKAGE (TOP VIEW)



SN54HC563 . . . FK PACKAGE (TOP VIEW)



OE does not affect internal operations of the latches. Old data can be retained or new data can be entered while the outputs are in the high-impedance state.

The SN54HC563 is characterized for operation over the full military temperature range of –55°C to 125°C. The SN74HC563 is characterized for operation from –40°C to 85°C.

FUNCTION TABLE (each latch)

	INPUTS	OU <u>T</u> PUT	
OE	LE	D	Q
L	Н	Н	L
L	Н	L	Н
L	L	Χ	\overline{Q}_0
Н	Χ	Χ	Z

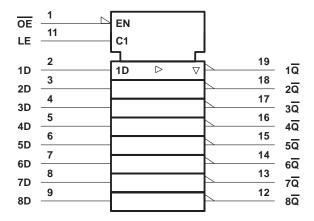


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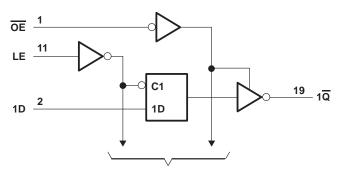
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logic symbol†



[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

logic diagram (positive logic)



To Seven Other Channels

absolute maximum ratings over operating free-air temperature range‡

Supply voltage range, V _{CC}	–0.5 V to 7 V
Input clamp current, I_{IK} ($V_I < 0$ or $V_I > V_{CC}$) (see Note 1)	
Output clamp current, I_{OK} ($V_O < 0$ or $V_O > V_{CC}$) (see Note 1)	
Continuous output current, I_O ($V_O = 0$ to V_{CC})	±35 mA
Continuous current through V _{CC} or GND	±70 mA
Package thermal impedance, θ_{JA} (see Note 2): DW package	97°C/W
N package	67°C/W
Storage temperature range, T _{stg}	. −65°C to 150°C

[‡] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.



^{2.} The package thermal impedance is calculated in accordance with JESD 51, except for through-hole packages, which use a trace length of zero.

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recommended operating conditions

			SI	SN54HC563		SN	174HC56	3	LINUT
			MIN	NOM	MAX	MIN	NOM	MAX	UNIT
Vcc	Supply voltage		2	5	6	2	5	6	V
		V _{CC} = 2 V	1.5			1.5			
V_{IH}	High-level input voltage	V _{CC} = 4.5 V	3.15			3.15			V
		VCC = 6 V	4.2			4.2			
		V _{CC} = 2 V	0		0.5	0		0.5	
V_{IL}	Low-level input voltage	V _{CC} = 4.5 V	0		1.35	0		1.35	V
		VCC = 6 V	0		1.8	0		1.8	
٧ _I	Input voltage		0		VCC	0		VCC	V
٧o	Output voltage		0		VCC	0		VCC	V
		V _{CC} = 2 V	0		1000	0		1000	
t _t	Input transition (rise and fall) time	V _{CC} = 4.5 V	0		500	0		500	ns
		V _{CC} = 6 V	0		400	0		400	
TA	Operating free-air temperature		-55		125	-40		85	°C

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CO	NDITIONS	Vaa	Т	A = 25°C	;	SN54H	IC563	SN74H	C563	UNIT			
PARAMETER	1551 CC	CNDITIONS	Vcc	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNII			
			2 V	1.9	1.998		1.9		1.9					
		I _{OH} = -20 μA	4.5 V	4.4	4.499		4.4		4.4					
Voн	$V_I = V_{IH}$ or V_{IL}		6 V	5.9	5.999		5.9		5.9		V			
		$I_{OH} = -6 \text{ mA}$	4.5 V	3.98	4.3		3.7		3.84					
		$I_{OH} = -7.8 \text{ mA}$	6 V	5.48	5.8		5.2		5.34					
	$V_{I} = V_{IH} \text{ or } V_{IL}$ $I_{OL} = 20 \mu\text{A}$ $I_{OL} = 6 \text{mA}$		2 V		0.002	0.1		0.1		0.1				
		I _{OL} = 20 μA	4.5 V		0.001	0.1		0.1		0.1				
VOL			6 V		0.001	0.1		0.1		0.1	V			
						I _{OL} = 6 mA	4.5 V		0.17	0.26		0.4		0.33
		$I_{OL} = 7.8 \text{ mA}$	6 V		0.15	0.26		0.4		0.33				
lį	$V_I = V_{CC}$ or 0		6 V		±0.1	±100		±1000		±1000	nA			
loz	$V_O = V_{CC}$ or 0		6 V		±0.01	±0.5		±10		±5	μΑ			
Icc	$V_I = V_{CC}$ or 0,	IO = 0	6 V			8		160		80	μΑ			
Ci		·	2 V to 6 V		3	10		10		10	pF			

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timing requirements over recommended operating free-air temperature range (unless otherwise noted)

		Vaa	T _A = 2	25°C	SN54H	IC563	SN74H	C563	UNIT
		VCC	MIN	MAX	MIN	MAX	MIN	MAX	UNIT
		2 V	80		120		100		
t _W	Pulse duration, LE high	4.5 V	16		24		20		ns
		6 V	14		20		17		
	Setup time, data before LE↓	2 V	50		75		63		
t _{su}		4.5 V	10		15		13		ns
		6 V	9		13		11		
	Hold time, data after LE↓	2 V	5		5		5		ns
t _h		4.5 V	5		5		5		
		6 V	5		5		5		

switching characteristics over recommended operating free-air temperature range, C_L = 50 pF (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	то	Vaa	T	T _A = 25°C		SN54H	IC563	SN74H	C563	UNIT	
PARAMETER	(INPUT)	(OUTPUT)	VCC	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT	
			2 V		77	175		265		220		
	D	Q	4.5 V		26	35		53		44		
			6 V		23	30		45		37		
^t pd			2 V		90	175		265		220	ns	
	LE	Any Q	4.5 V		27	35		53		44		
			6 V		23	30		45		37		
		Any Q	2 V		70	150		225		190		
t _{en}	ŌĒ		Any Q	Any Q	4.5 V		24	30		45		38
			6 V		21	26		38		32		
			2 V		47	150		225		190		
^t dis	ŌĒ	Any Q	4.5 V		23	30		45		38	ns	
			6 V		21	26		38		32		
			2 V		28	60		90		75		
t _t		Any Q	4.5 V		8	12		18		15	ns	
			6 V		6	10		15		13		

SN54HC563, SN74HC563 **OCTAL TRANSPARENT D-TYPE LATCHES** WITH 3-STATE OUTPUTS SCLS145B - DECEMBER 1982 - REVISED MAY 1997

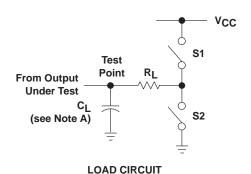
switching characteristics over recommended operating free-air temperature range, C_L = 150 pF (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	то	Vaa	T,	T _A = 25°C		SN54H	IC563	SN74H	C563	UNIT		
PARAMETER	(INPUT)	(OUTPUT)	VCC	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNII		
				2 V		95	200		300		250		
	D	Q	4.5 V		33	40		60		50			
.			6 V		29	34		51		43			
^t pd	LE Any $\overline{\mathbb{Q}}$		2 V		103	225		335		285	ns		
		Any Q	Any Q	Any Q	4.5 V		33	45		67		57	
				6 V		29	38		57		48		
			2 V		85	200		300		250			
t _{en}	ŌE	Any Q	4.5 V		29	40		60		50	ns		
			6 V		26	34		51		43			
			2 V		60	210		315		265			
t _t			Any Q	4.5 V		17	42		63		53	ns	
			6 V		14	36		53		45			

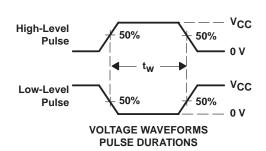
operating characteristics, $T_A = 25^{\circ}C$

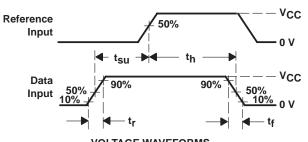
PARAMETER		TIONS TYP	UNIT
C _{pd} Power dissipation capacitance per latch	No load	50	pF

PARAMETER MEASUREMENT INFORMATION

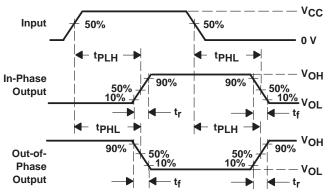


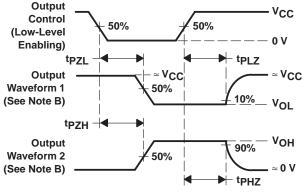
		_			
PARA	METER	RL	CL	S1	S2
t	t _{PZH} 50 pF 1 kΩ or	Open	Closed		
ten t	tPZL	150 pF		Closed	Open
tdis	tPHZ	1 k Ω	50 pF	Open	Closed
ais	tPLZ	1 K32	30 pi	Closed	Open
t _{pd} or t _t		_	50 pF or 150 pF	Open	Open





VOLTAGE WAVEFORMS
SETUP AND HOLD AND INPUT RISE AND FALL TIMES





VOLTAGE WAVEFORMS
PROPAGATION DELAY AND OUTPUT TRANSITION TIMES

VOLTAGE WAVEFORMS
ENABLE AND DISABLE TIMES FOR 3-STATE OUTPUTS

NOTES: A. C_L includes probe and test-fixture capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. Phase relationships between waveforms were chosen arbitrarily. All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, $Z_O = 50~\Omega$, $t_\Gamma = 6$ ns, $t_f = 6$ ns.
- D. The outputs are measured one at a time with one input transition per measurement.
- E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
- F. tpzL and tpzH are the same as ten.
- G. tpLH and tpHL are the same as tpd.

Figure 1. Load Circuit and Voltage Waveforms



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